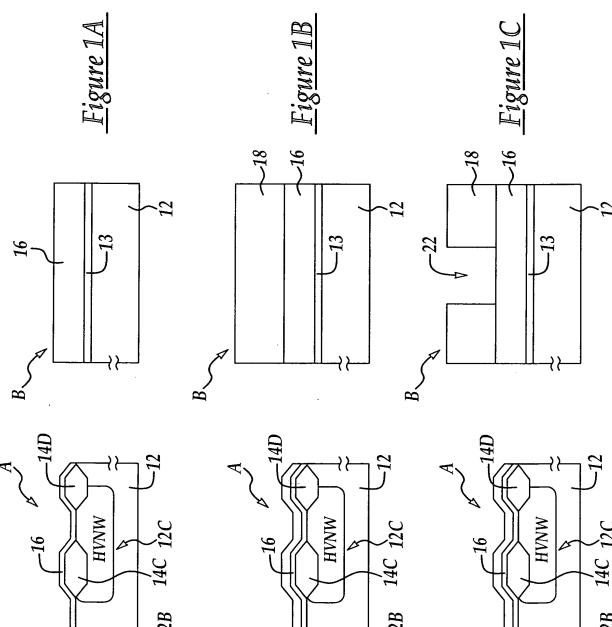
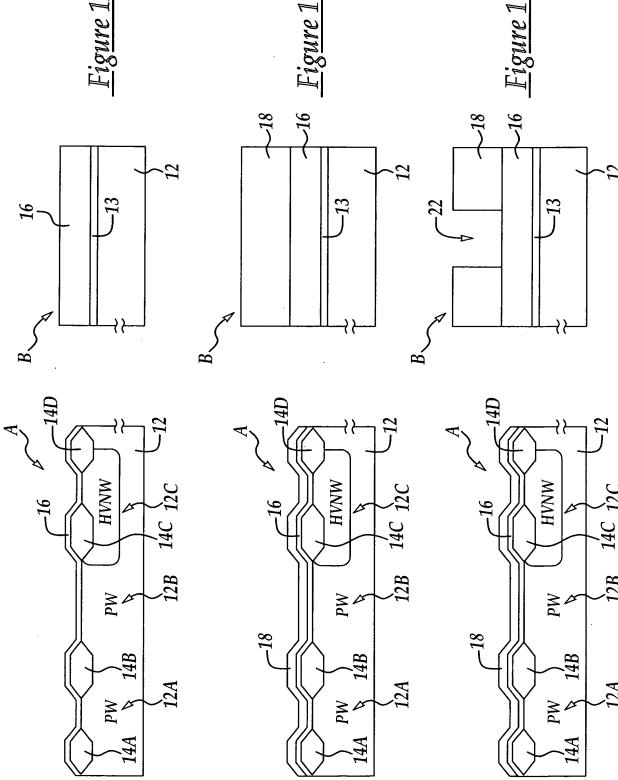
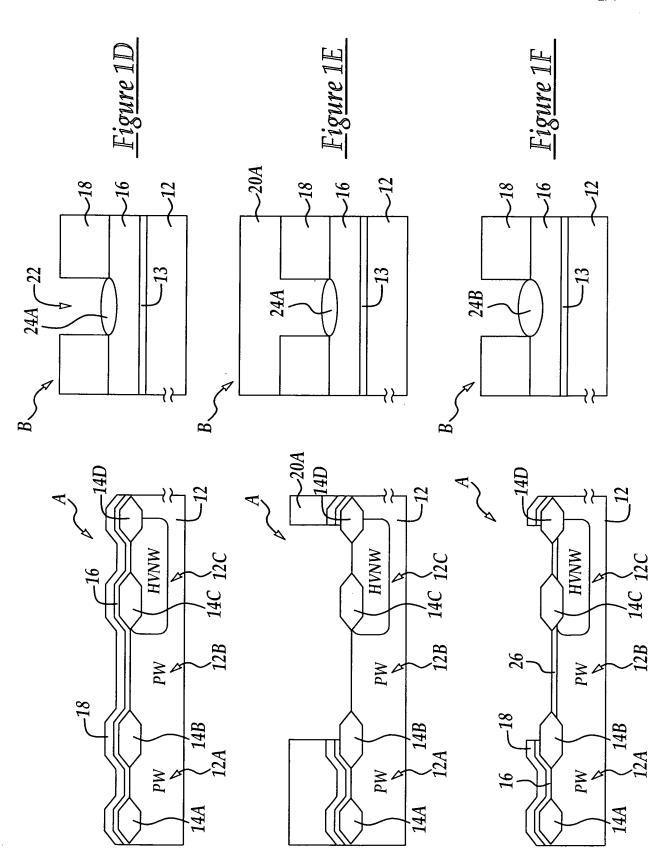
Inventor: HAW-CHUAN WU
Serial No.: To Be Assigned Filed: Herewith
For: Method Of Integrated Manufacturing Of Split Gate Flash Memory With High Voltage Mosfets
Attorney Doc. No.: 67,200-1103





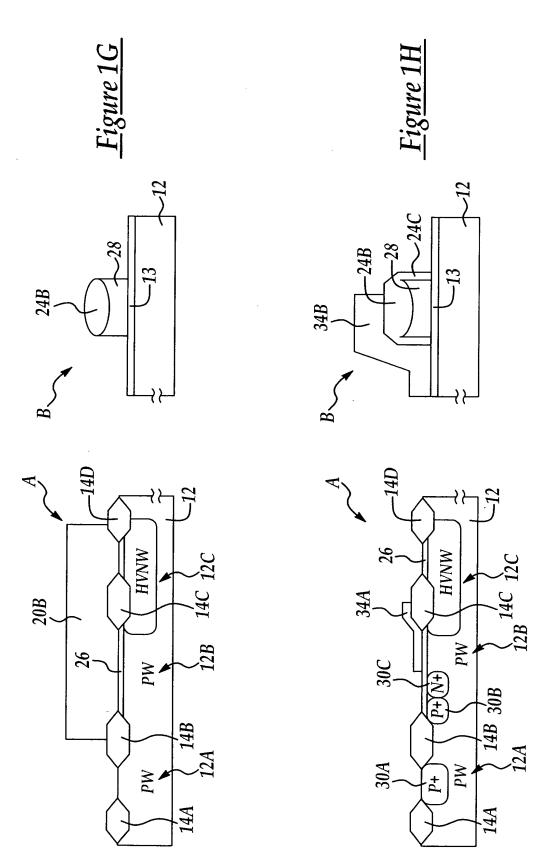
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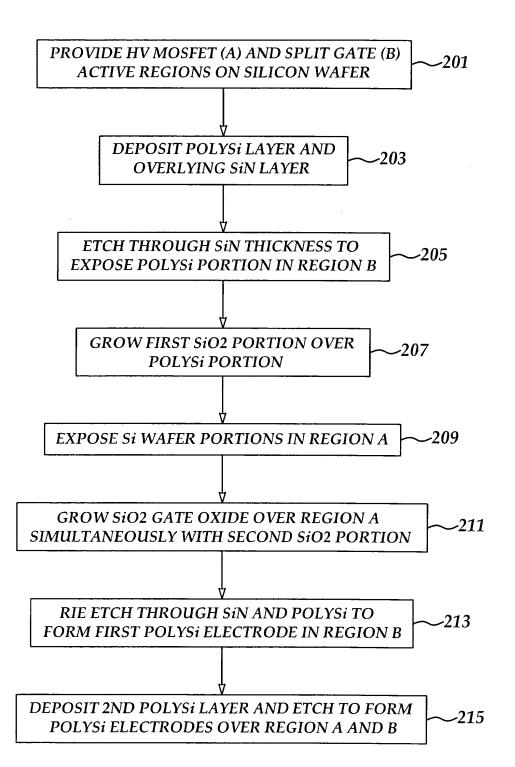


Figure 2